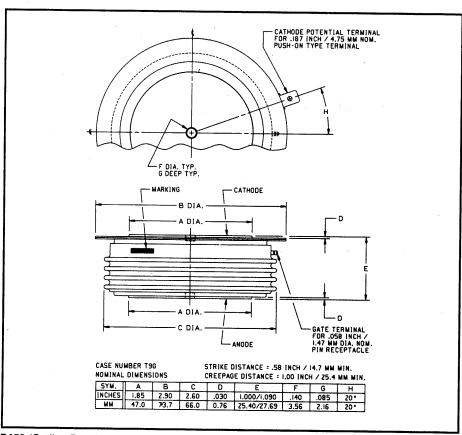


Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272
Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

Phase Control SCR 1640 Amperes Average 1600 Volts



C450 (Outline Drawing)

Ordering Information:

Select the complete five or six digit part number you desire from the table, i.e. C450PM is a 1600 Volt, 1640 Ampere Phase Control SCR.

Туре	Volt	Current	
	V _{DRM} V _{RRM}	Code	lT(av)
450	600	М	1640
	800	N	
	1000	Р	
	1200	PB	
	1400	PD	
	1600	PM	



C450 Phase Control SCR 1640 Amperes Average, 1600 Volts

Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak, hermetic Pow-R-Disc devices employing the field proven amplifying gate.

Features:

- ☐ Low On-State Voltage
- ☐ High di/dt Capability
- ☐ High dv/dt Capability
- ☐ Hermetic Packaging
- Excellent Surge and I²t Ratings

Applications:

- ☐ Power Supplies
- VAR Generators



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

C450 Phase Control SCR 1640 Amperes Average, 1600 Volts

Absolute Maximum Ratings

Characteristics	Symbol	C450	Units Volts	
Non-repetitive Transient Peak Reverse Voltage	V _{RSM}	V _{RRM} + 100V		
RMS On-state Current, T _C = 65°C	^I T(rms)	2575	Amperes	
Average Current 180° Sine Wave, T _C = 65°C	I _{T(av)}	1640	Amperes	
RMS On-state Current, T _C = 55°C	l _{T(rms)}	2790	Amperes	
Average Current 180° Sine Wave, T _C = 55°C	I _{T(av)}	1780	Amperes	
Peak One Cycle Surge On-state Current (Non-repetitive) 60Hz	l _{tsm}	28500	Amperes	
Peak One Cycle Surge On-state Current (Non-repetitive) 50Hz	l _{tsm}	26000	Amperes	
Critical Rate-of-rise of On-state Current (Non-repetitive)	di/dt	800	A/μsec	
Critical Rate-of-rise of On-state Current (Repetitive)	di/dt	400	A/μsec	
I ² t (for Fusing) for One Cycle, 60Hz	ı ² t	3.4 x 10 ⁶	A ² sec	
Peak Gate Power Dissipation	P _{GM}	200	Watts	
Average Gate Power Dissipation	. P _{G(av)}	5	Watts	
Operating Temperature	Ţ _i	-40 to +125°C	°C	
Storage Temperature	T _{stg}	-40 to +150°C	°C	
Approximate Weight		1	lb.	
		454	g	
Mounting Force		5500 to 6000	lb.	
·		2450 to 2670	kg.	



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

C450
Phase Control SCR

1640 Amperes Average, 1600 Volts

Electrical Characteristics, $T_j = 25^{\circ}C$ Unless Otherwise Specified

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Repetitive Peak Reverse Leakage Current	IRRM	T _j = 125°C, V _R = V _{RRM}		.,,,,	45	mA
Repetitive Peak Forward Leakage Current	IDRM	T _j = 125°C, V _D = V _{DRM}			45	
Peak On-state Voltage	V _{TM}	I _{TM} = 3000A Peak				mA
		Duty Cycle < 0.1%			1.4	Volts
Threshold Voltage, Low-level	V _{(TO)1}	$T_j = 125^{\circ}\text{C}, I = 15\%, I_{\text{T}}(av) \text{ to } \pi I_{\text{T}}(av)$				
Slope Resistance, Low-level		1) 120 0, 12 1076, 11 (av) 10 /uT(av)			0.6768	Volts
Threshold Voltage, High-level	V _{(TO)2}	$T_j = 125$ °C, $I = \pi I_{T(av)}$ to I_{TSM}			0.1925	mΩ
Slope Resistance, High-level	r _{T2}				1.1978	Volts
V _{TM} Coefficients, Low-level		$T_j = 125$ °C, $I = 15\% I_{T(av)} to \pi I_{T(av)}$			0.0937	mΩ
) (av) to M((av)		,	. 0.100	.0.5
					$N_1 = 0.106$ $N_1 = 0.047$	
					$G_1 = 0.047$ $G_1 = 9.845$	
N On the contract of the contr					$\theta_1 = 0.045$	
V _{TM} Coefficients, High-level		$T_j = 125$ °C, $I = \pi I_{T(av)}$ to I_{TSM}	· · · · · ·	_	1 0.010	
		(4, 7, 1, 2, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1,		A	₂ = -2.571	9
					2 = 0.547	
					_ 2 = 1.157	
Typical Delay Time				D	_ 2 = -0.014	735
Typical Delay Time	^t d	$I_T = 50A$, Gate = 20V, 20 Ω ,		0.7		μsec
Typical Turn-off Time		0.1μsec Rise				
rypical furn-off time	^t q	$T_j = 125$ °C, $I_T = 2000$ A,		150		μsec
		di _R /dt = 25A/μsec Reapplied				,
		$dv/dt = 200V/\mu sec$ Linear to				
		V_{DRM} , $V_{R} = 50V$,				
Minimum Critical dv/dt - Exponential to VDRM		Gate = 0V, $R_{GK} = 100\Omega$				
Gate Trigger Current	dv/dt	T _j = 125°C	400			V/µsec
sate riigger current	^I GT	T _j = 25°C,			200	mA
		$V_D = 20V_{DC}, R_L = 3\Omega$				
Gate Trigger Voltage	v_{GT}	$T_{j} = -40^{\circ}\text{C to } +125^{\circ}\text{C},$			5.0	Volts
		$V_D = 20V, R_L = 3\Omega$			0.0	VOILS
Ion-Triggering Gate Voltage	V _{GDM}	T _i = 125°C,			0.15	\/-lk-
		$V_D = V_{DRM}$, $R_L = 1000\Omega$			0.15	Volts
Peak Forward Gate Current	^I GTM	- D - DRM, - L = 100032				
eak Reverse Gate Voltage	VGRM				10	A
	*GRM			-	5	Volts
hermal Characteristics						-
laximum Thermal Resistance, Double Sided Coo	lina					
unction-to-Case	_					
ase-to-Sink	R _{θ(j-c)}				0.025	°C/W
	$R_{\theta(c-s)}$				0.0075	°C/W



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

C450
Phase Control SCR
1640 Amperes Average, 1600 Volts

